# Phase diagram of orbital-selective $M$ ott transitions at $n$ ite tem peratures 

# Kensuke Inaba, A kinisa K oga, Sei-ichiro Suga and N orio K aw akami 

D epartm ent of A pplied P hysics, O saka U niversity, Suita, O saka 565-0871
(R eceived A pril 14, 2024)


#### Abstract

$M$ ott transitions in the tw o-orbitalH ubbard $m$ odelw ith di erent bandw idths are investigated at $n$ ite tem peratures. By m eans of the selfenergy functionalapproach, we discuss the stability of the interm ediate phase w ith one orbital localized and the other itinerant, which is caused by the orbital-selective M ott transition (O SM T). It is shown that the O SM T realizes tw o di erent coexistence regions at nite tem peratures in accordance $w$ ith the recent results of $L$ iebsch. W e further nd that the particularly interesting behavior em erges around the special condition $\mathrm{U}=\mathrm{U}^{0}$ and $\mathrm{J}=0$, which includes a new type of the coexistence region w ith three distinct states. By system atically changing the H und coupling, we establish the global phase diagram to elucidate the key role played by the $H$ und coupling on the $M$ ott transitions.


KEYW ORD S : O roitalselective M ott transition, Self-energy functional approach

Strongly correlated electron system $s$ with som e orbitals have been investigated extensively. ${ }^{1,2)}$ In particular, substantial progress in theoretical understanding of M ott transitions ofm ulti-orbital system s has been $m$ ade by dynam ical mean- eld theory (DMFT ${ }^{\beta, 4 \text { ) calcula- }}$ tions. ${ }^{5\{29)}$ Am ong them, the orbital-selective M ott transition (OSMT) ${ }^{30}$ ) in themulti-orbitalsystem with di erent bandw idths has been one of the $m$ ost active topics in this context. Typicalm aterials are $\mathrm{Ca}_{2} \quad{ }_{x} \mathrm{Sr}_{\mathrm{x}} \mathrm{RuO}_{4}{ }^{31)}$ and $\mathrm{La}_{\mathrm{n}+1} \mathrm{~N} \mathrm{i}_{1} \mathrm{O}_{3 n+1},{ }^{32,33)}$ where the OSMT is suggested to be realized by the chem ical substitution and the change in the tem perature. These experim ental ndings have stim ulated theoretical investigations on this issue. ${ }^{21\{30,34,35)}$ It has been clari ed by extensive works that in the tw O-orbitalsystem with di erent bandw idths at zero tem perature, the OSM T occurs in general and $m$ erges to a single $M$ ott transition in a certain restricted param eter region. ${ }^{22,24,25)}$ A lso, it has been realized that the $H$ und coupling is an im portant key param eter to understand the correct nature of the OSM T. ${ }^{28,36)}$

In contrast to the detailed analysis at zero temperature, system atic discussions at nite temperatures ${ }^{21,23,27,28)}$ are lacking. In particular, the stability of the interm ediate $m$ etallic phase $m$ ay be im portant to discuss the possibility of the OSM T in real materials. It is thus desirable to investigate the OSM T in the m ulti-orbitalm odel at nite tem peratures. $Q$ uite recently, Liebsch have studied nite-tem perature properties of the OSM T by DMFT combined with the exact diagonalization $m$ ethod, ${ }^{28)}$ where the O SM T occurs even at nite tem peratures.

In this paper, we give the detailed investigation of the OSM T in the two-orbital H ubbard m odel at zero and nite tem peratures. $W$ e $m$ ake use of the self-energy functional approach (SFA) proposed by Pottho ${ }^{37 \text { l }}$ which is e cient to study nite-tem perature properties, to determ ine the detailed phase diagram. T he present study provides the results com plem entary to Liebsch's in a certain param eter regim $e^{28)}$ and $m$ oreover establishes rich phase diagram s , which include a new type of the coexistence region $w$ th three distinct states. $W$ e further clarify
how the m agnitude of the $H$ und coupling controls the nature of phase diagram s at nite tem peratures.
$W$ e consider the tw o-orbital $H$ ubbard $m$ odel $w$ ith different bandw idths, which is given by the H am iltonian, $\mathrm{H}=\mathrm{H}_{0}+\underset{\mathrm{i}}{\mathrm{H}_{\mathrm{i}} \mathrm{H}} \mathrm{w}$ th

$$
\begin{align*}
& H_{0}=\quad \text { ( } \quad \text { ij) } C_{i}^{y} C_{j} \text {; }  \tag{1}\\
& \text { <i;j>; ; } \\
& \mathrm{X} \quad \mathrm{X} \\
& H_{i}^{0}=U^{X} \quad n_{i} n n_{i} \#+U_{0} \quad\left(U^{0} \quad 0 J\right) n_{i 1} n_{i 2} \quad 0
\end{align*}
$$

where $c_{i}^{y}\left(c_{i}\right)$ is the creation (annihilation) operator of an electron at the ith site w ith spin (=";\#) and orbital $(=1 ; 2)$, and $n_{i}=c_{i}^{y} c_{i}$. Here, $t$ denotes the hopping integral for orbital , the chem ical potential, $U\left(U^{0}\right)$ the intra-orbital (inter-orbital) C oulomb interaction, and $J$ the $H$ und coupling including the spin-
ip and pair-hopping term s. In the follow ing, we im pose the condition $U=U^{0}+2 \mathrm{~J}$, which results from rotational sym $m$ etry of degenerate orbitals.

In order to discuss the M ott transitions at zero and nite tem peratures, w e use here the self-energy functional approach SFA, ${ }^{37)}$ which is based on the Luttinger-W ard variational m ethod. ${ }^{38)} \mathrm{T}$ his approach allow s us to deal $w$ ith nite-tem perature properties of the multi-orbital system e ciently, ${ }^{39)}$ where standard DMFT w ith num ericaltechniquesm ay encounter som e di culties in a practical com putation when the num ber of orbitals increases.

In SFA, one $m$ akes use of the fact that the Luttinger$W$ ard functional does not depend on the detail of the H am iltonian $\mathrm{H}_{0}$ as far as the interaction term $\mathrm{H}^{0}$ is unchanged. ${ }^{37)}$ This enables us to introduce a proper reference system with the same interaction term. O ne of the sim plest $m$ odels for the reference system $P^{\text {is explicitly }}$ given by the follow ing H am iltonian, $\mathrm{H}_{\text {ref }}=\mathrm{P}_{\mathrm{i}}^{\mathrm{H}}{ }_{i}^{(\text {i) }}$ (ef ,

$$
\begin{equation*}
+\mathrm{X}^{(\mathrm{i})}\left(\mathrm{C}_{\mathrm{i}}^{\mathrm{y}} \mathrm{a}^{(\mathrm{i})}+\mathrm{H}: \mathrm{C}:\right)+\mathrm{H}_{\mathrm{i}}^{0} \text {; } \tag{3}
\end{equation*}
$$

where $a^{(i) y}\left(a^{(i)}\right)$ creates (anninilates) an electron w ith spin and orbital, which is connected to the ith site in the original lattige. This approxim ation is regarded as a nite-tem perature extension of the two-site DMFT40) in som e respects. In this paper, we $x$ the param eters $0=0 ;=$ and $=U=2+U^{0} \quad \mathrm{~J}=2$ to discuss the zero and nite tem perature properties at half lling. By choosing the param eters V to m inim ize the grand potential, $@=@ V=0(=1 ; 2)$, we can nd a proper reference H am ittonian, which approxim ately describes the original correlated system .

W e note that the hybridization $V$ betw een a given site on the original lattice and a site in the reference system $m$ ay be regarded as the renorm alized bandw idth of the
-orbitalband. For exam ple, for $s m$ all V , heavy quasiparticles are form ed in the band, and atV $=0$ the sys tem is driven to the M ott insulating state. B y calculating hybridizations $V_{1}$ and $V_{2}$, we thus discuss the stability of the $m$ etallic state in our tw o-orbital H ubbard model. In the follow ing, we focus on the system $w$ ith $W_{1}=2: 0$ and $W_{2}=4: 0$ to discuss $M$ ott transitions, $W$ here $W$ is the bandw idth of orbital for the sem i-circular density of states $(D O S), \quad(x)=4=W \quad \overline{1} \quad(2 x=W)^{2}$.

W e begin our discussions w ith the M ott transitions at zero tem perature for a typical choice of the ratio of the param eters, $\mathrm{U}^{0}=0: 5 \mathrm{U}$ and $\mathrm{J}=0: 25 \mathrm{U}$. Figure 1 shows the contour plots of the grand potential and the corresponding entropy per site $S=L$ at the stationary point, where $L$ is the num ber of sites. W hen the C oulomb interaction is sm all ( $\mathrm{U}=2: 3$ ), the stationary point, where the grand potential is m inim ized, is located around $\left(V_{1} ; V_{2}\right) \quad(0: 14 ; 0: 55)$. This im plies that the ef-


Fig. 1. The entropy per site $S=L$ as a function of $U W$ ith xed ratios $U^{0}=0: 5 \mathrm{U}$ and $\mathrm{J}=0: 25 \mathrm{U}$ at $\mathrm{T}=0$. Inset show S the contour plot of the grand potential for (a) $U=2: 3$, (b) 2.8 and (c) 3.6,w here crosses denote the $m$ in im a of the grand potential.
fective bandw idth for each orbital state is nite, stabilizing the $m$ etallic ( $M$ ) phase. Increasing the interaction, the stationary point of the system touches the $V_{2}$-axis as
shown in the inset (b): the e ective bandw idth for the narrow er band $V_{1}$ vanishes while $V_{2}$ still rem ains nite. Therefore, the O SM T occurs, where one band is insulating and the other is stillm etallic.W e refer to this phase as the O SM phase in the follow ing. It is seen that the residual entropy in the $O S M$ phase is $S=L=\log 2$, im plying the form ation of free localized $s=1=2$ spins. Further increase of the interaction induces the M ott transition in the other band to the $M$ ott insulating (M I) phase, where $V_{1}=V_{2}=0$ as shown in the inset (c). In this case, the localized spins for tw o bands form the triplet state due to the $H$ und coupling, so that the residualentropy $S=L=\log 3$ in the region $U>3: 4 . N$ ote that the residualentropy at zero tem perature is an artifact of our simpli ed SFA approach. This pathologicalbehavior can be som ehow im proved, e.g. by taking into account spin
uctuations m ore accurately. At zero tem perature, we can nd no other local minim a in the grand potential when the interaction is varied. T herefore, we clearly observe double second-order M ott transitions in the m ultiorbitalsystem, which indeed con m s the claim of K oga et $a l^{22)}$ for the O SM transition obtained by $m$ eans of D M FT com bined w ith the exact diagonalization.

W e now m ove to the phase diagram at nite tem peratures. Since each transition at zero tem perature is sim ilar to that for the single-orbital H ubbard model, 3) the rst-order transition $m$ ay occur at nite tem peratures around each criticalpoint, as show $n$ in ref. 28. In fact, we nd that when the system belongs to the m etallic phase close to the critical point, tw o stationary points representing the $M$ and O SM states appear sim ultaneously once the system is at nite temperatures ( $T=0: 002$ ), as show $n$ in $F i g .2$. T he doublew ell structure causes the


Fig. 2. (a) $T$ he contour plot of the grand potential $\left(V_{1} ; V_{2}\right)$ at $\mathrm{T}=0: 002 ; \mathrm{U}=2: 3$ and $\mathrm{J}=0: 25 \mathrm{U} . \mathrm{T}$ wom in im a coexist, which correspond to the M and OSM states. (b) The entropy vs the interaction $U$ at $T=0: 002 ; \mathrm{J}=0: 25 \mathrm{U}$.
rst-order M ott transition with hysteresis at nite tem peratures ( F ig. 2 (b)). At $T=0: 002$, as $U$ increases, the stationary point for the $m$ etallic state disappears around $U_{c 2} \quad 2: 36$, where the M ott transition occurs to the OSM phase. On the other hand, as U decreases, the O SM phase realized is stable down to $U_{c 1} \quad 2: 24$. The rst-order transition point $U_{C} \quad 2: 33$ for $T=0: 002$ is determ ined by the crossing point of the two m in im a in the grand potential. The obtained phase diagram is shown in $F$ ig. 3. It is found that the two distinct coexistence regions appear around $U \quad 2: 4$ and $U \quad 3: 3 . T$ he phase


Fig. 3. U $T$ phase diagram at $J=0: 25 \mathrm{U}$. T here are two $\mathrm{co}-$ existence phases, which are featured by the triangular-shaped regions: (left) the $m$ etallic phase and orbital-selective M ott phase coexist and (right) onbital-selective $M$ ott phase and insulating phase coexist.


Fig. 4. (a) Entropy $S=L$ and (b) Speci $c$ heat $C=L$ as a function of $U$ in the crossover region, $J=0: 25 U$.
boundaries $U_{c 1}, U_{c 2}$ and $U_{C} m$ erge at the critical tem perature $\mathrm{T}_{\mathrm{c}}$ for each transition. Sim ilar phase diagram was recently obtained by Liebsch by means of DMFT w ith the exact diagonalization $m$ ethod, who gave better esti$m$ ates of the critical tem peratures. ${ }^{28)} \mathrm{N}$ evertheless, our SFA treatm ent elucidates further interesting properties such as the crossover behavior am ong the com peting $M$, O SM and M I phases. To m ake this point $m$ ore explicit, we calculate them odynam ic quantities such as the entropy and the speci cheat, which are displayed in Fig. 4. W e can see a double-step structure sim ilar to that found at zero tem perature in the curve of the entropy. Such anom alies are $m$ ore clearly seen in the speci cheat. It is quite im pressive that the crossoverbehavior am ong three phases are clearly seen even at higher tem peratures. W e can thus say that the OSM phase is rather well de ned even at higher tem peratures above the critical tem pera-
tures.
W e have so far discussed the OSM T for the system w th rather large $H$ und couplings. A ccording to the zerotem perature analysis, ${ }^{22,24,25)}$ it is know $n$ that around the special condition $U=U^{0}$ and $J=0$ at $W_{1}=W_{2}=0: 5$, a non-trivial single $M$ ott transition occurs, whose origin is attributed to enhanced orbital uctuations. ${ }^{23)}$ Therefore, it is interesting to observe what happens at nite tem peratures, when the system approaches the condition $U=U^{0}$ and $J=0$. By perform ing sim ilar calculations, we end up w ith the phase diagram for the system $w$ ith $\mathrm{U}^{0}=0: 94 \mathrm{U} ; \mathrm{J}=0: 03 \mathrm{U}$ (Fig. 5). Since the H und coupling is very sm all in this case, two critical points for the OSM T at zero tem perature are close to each other. O ne of the m ost rem arkable ndings here is that three com peting states ( $M$, O SM and M I states) coexist in a certain region at nite tem peratures, where three distinct localm inim a appear in the grand potential, as show $n$ in the inset. In these param eters, the coexistence regions


Fig. 5. U $T$ phase diagram at $J=0: 03 \mathrm{U}$ : we have used the sam e sym bols as in Fig. 3. N ote that the two coexistence regions are not separated here in contrast to F ig. 3. Three distinct states ( $M, O S M$, and M I states) coexist in the region which is surrounded by lled and open circles. Inset shows the contour plot of the ground potential in the coexistence region for $U=4: 45 ; T=0: 004$, where there are three localm in $\dot{m} a$.
are quite sensitive to how large the H und coupling is.
To observe how the H und coupling controls nitetem perature properties, we show the global phase diagram s in Fig. 6 by system atically changing J.As the $H$ und coupling decreases, both the critical points $U_{c 2}^{(1)}$ and $U_{c 2}^{(2)}$ increase $m$ onotonically, stabilizing the $m$ etallic state up to fairly large C oulom b interactions, as already $m$ entioned for the zero-tem perature case. ${ }^{22)}$ A rem ank$a b l e$ feature in $F$ ig. 6 is that the completely di erent behavior em erges in the critical tem peratures $T_{c}{ }^{(1)}$ and $\mathrm{T}_{\mathrm{c}}^{(2)}$. It is seen that $\mathrm{T}_{\mathrm{c}}{ }^{(1)}$ is alm ost unchanged, whereas $\mathrm{T}_{\mathrm{c}}{ }^{(2)}$ strongly depends on the H und coupling. T his m ay be explained as follow s. A round the rst boundary between the M and OSM phases, the nature of the transition is essentially the same as the single-orbital case, as discussed above. Therefore, the $H$ und coupling litthe $a$ ects the critical tem perature $\mathrm{I}_{\mathrm{c}}^{(1)}$. On the other


Fig. 6. O verall picture for the coexistence regions $w$ ith system atic change of $J$ : two types of the regions are shown for $J=$ $0: 25 \mathrm{U} ; \mathrm{J}=0: 1 \mathrm{U}, \mathrm{J}=0: 03 \mathrm{U}$ and $\mathrm{J}=0$ from left to right. At $J=0$, the transition from the $m$ etal to $O S M$ disappears.
hand, around the second phase transition betw een the OSM and M I phases, orbital uctuations should play a vital role. T he presence of the $H$ und coupling som ew hat suppresses orbital uctuations due to the form ation of the triplet state. ${ }^{15)}$ Therefore, as J decreases, enhanced orbital uctuations raise the critical tem perature $\mathrm{I}_{c}{ }^{(2)}$, as seen in $F$ ig. 6. N ote that for very $s m$ all $H$ und couplings ( J . 0:03U ) the O SM phase disappears, ${ }^{25)}$ and thus the nite as wellas zero-tem perature properties can be approxim ately described by the $m$ ulti-orbital $m$ odel $\left(\mathrm{U} \in \mathrm{U}^{0}\right)$ w ith the sam e bandw idths. ${ }^{15,17,19,39)}$

In summ ary, we have investigated M ott transitions in the two-orbital $H$ ubbard $m$ odel $w$ ith di erent band$w$ idths at nite tem peratures. By $m$ eans of the selfenergy functional approach, we have con $m$ ed that two distinct coexistence regions appear in the phase diagram in accordance w ith the recent results obtained by DMFT.A notable new nding is that the OSM phase is rather well de ned even at tem peratures higher than the two critical tem peratures. Further rem arkable features have been elucidated in the phase diagram around special conditions with sm all H und couplings J ' 0 ( $U^{\prime} U^{0}$ ), where the coexistence region w ith three com peting phases em erges. 0 rbital uctuations are enhanced there, and therefore the system gets very sensitive to sm allperturbations, giving rise to the rich phase diagram at low tem peratures. W e have also clari ed the role of the H und coupling on global features in the phase diagram: the $H$ und coupling has little (sizable) e ect on the transition between the M and OSM (O SM and M I) phases, which is again attributed to the role played by enhanced orbital uctuations.

In this paper we have exploited the sim pli ed version ofSFA to elucidate fundam entalproperties at nite tem peratures. Since instabilities to possible ordered phases have not been considered here, SFA is to be generalized to inconporate such ordered phases, which should be done in the future work.

W e would like to thank M. Sigrist, T. M . R ice and A. Liebsch for valuable discussions. N um erical com putations w ere carried out at the Supercom puter C enter, the Institute for Solid State Physics, University of Tokyo.

This work was supported by a G rant-in-A id for Scienti c Research from the M inistry of Education, Culture, Sports, Science, and Technology, Japan.

1) M. Im ada, A. Fu j̈m ori and Y. Tokura: Rev. M od. Phys. 70 (1998) 1039.
2) Y.Tokura and N.N agaosa: Science 288 (2000) 462.
3) A. G eorges, G . K otliar, $W$. K rauth and M.J.R ozenberg: $R$ ev. M od. Phys. 68 (1996) 13.
4) G. K otliar and D . Vollhardt: Phys. Today 57 (2004) 53.
5) C.-I.K im , Y.K uram oto and T.K asuya: J.P hys. Soc.Jpn. 59 (1990) 2414.
6) G. K otliar and H. K a jueter: P hys. R ev. B 54 (1996) 14221.
7) M.J. R ozenberg: Phys. Rev. B 55 (1997) R 4855.
8) J. B unem ann and W.W eber, Phys. Rev. B 55, 4011 (1997); J. B unem ann and W . W eber and F. G ebhard, ibid 57, 6896 (1998).
9) H. H asegaw a: J. P hys. Soc. Jpn. 56 (1997) 1196.
10) K.H eld and D . Vollhardt: Eur. Phys. J. B 5 (1998) 473.
11) J.E.H an, M . Jarrel and D. L. C ox: Phys. Rev.B 58 (1998) R 4199.
12) T.M om oi and K.K ubo:Phys. Rev.B 58 (1998) R 567.
13) A. K lej̇hberg and J. Spalek: P hys. Rev. B 57 (1998) 12401.
14) Y. Im ai and N . K aw akam i: J. Phys. Soc. Jpn 70 (2001) 2365.
15) A.K oga and Y .Im aiand N .K aw akam i:P hys.R ev.B 66 (2002) 165107; J. P hys. Soc. Jpn. 72 (2003) 1306.
16) V. S. O udovenko and G. K otliar: Phys. Rev. B 65 (2002) 075102.
17) Y. O no, M . Pottho and R. Bulla: Phys. Rev. B 67 (2003) 035119.
18) Y.Tom io and T. O gaw a: ond-m at/0407314.
19) T.Pruschke and R.Bulla:Eur. Phys. J.B 44 (2005) 217.
20) S. Sakai, R.A rita and H.A oki: cond-m at/0405503.
21) A.Liebsch, P hys.R ev.Lett.91, 226401 (2003); E urophys.Lett. 63, 97 (2003); Phys. Rev. B 70, 249904 (2004).
22) A. K oga, N.K aw akam i, T.M.R ice and M. Sigrist: P hys. R ev. Lett. 92 (2004) 216402.
23) A. K oga, N. K aw akam i, T . M . R ice and M . Sigrist: condm at/0503651.
24) M . Ferrero, F. Becca, M . Fabrizio and M . C apone: condm at/0503759.
25) L. de' M edici, A. Georges and S. B ierm ann: condm at/0503764.
26) R.A rita and K. H eld: cond-m at/0504040.
27) C. K necht, N. B lum er and P. G. J. van D ongen: condm at/0505106.
28) A fter the com pletion of the present work, we becam e aw are of the recent preprint; A. L iebsch: cond-m at/0505393.
29) S. B ierm ann, L. de' M edici and A. Georges: condm at/0505737.
30) V. I. A nisim ov, I. A. N ekrasov, D.E.K ondakov, T.M.R ice and M . Sigrist: Eur. P hys. J.B 25 (2002) 191.
31) S.N akatsu \#̈et al:: P hys.R ev.Lett. 90 (2003) 137202; S.N akatsu ji and Y.M aeno: P hys. R ev. Lett. 84 (2000) 2666.
32) K. Sreedhar: et al., J. Solid State C om m. 110 (1994) 208; Z. Zhang, et al: J. Solid State Comm. 108 (1994) 402; 117 (1995) 236.
33) Y. K obayashi, S. Taniguchi, M . K asai, M . Sato, T. N ishioka and M . K ontani: J. P hys. Soc. Jpn 65 (1996) 3978.
34) M . Sigrist and M . Troyer: E ur. P hys. J. B 39 (2004) 207.
35) Z.Fang, N.N agaosa and K .Terakura:Phys.Rev.B 69 (2004) 45116.
36) A. K oga, N. K aw akam i, T. M. R ice and M. Sigrist: condm at/0406457.
37) M . Pottho : Eur. Phys. J.B 32 (2003) 429; M .Pottho : ibid 36 (2003) 335; K . Pozgajcic: cond-m at/0407172.
38) J.M . Luttinger: Phys. Rev. 118 (1960) 1417.
39) K. Inaba, A. K oga, S. Suga and N. K awakam i: condm at/0506150.
40) M . Pottho : Phys. Rev. B 64 (2001) 165114.
